

2 July 2015 Product data sheet

1. General description

Double PNP switching transistor in a very small SOT363 (TSSOP6) Surface-Mounted Device (SMD) plastic package.

Double NPN complement: PMBT4401YS

2. Features and benefits

- Double general-purpose switching transistor
- AEC-Q101 qualified

3. Applications

Switching and linear amplification

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
|-----------------|---------------------------|--|--|-----|-----|------|------|--|
| Per transistor | Per transistor | | | | | | | |
| h _{FE} | DC current gain | V_{CE} = -2 V; I_{C} = -150 mA; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | | 100 | - | 300 | | |
| Per transistor | | | | | | | - | |
| V_{CEO} | collector-emitter voltage | open base | | - | - | -40 | V | |
| I _C | collector current | | | - | - | -600 | mA | |



40V, 600 mA double PNP switching transistor

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|---------------|--|----------------|
| 1 | E | emitter TR1 | 654 | 6 5 4 |
| 2 | В | base TR1 | | P = 200 |
| 3 | С | collector TR2 | 0 | TR1 TR2 |
| 4 | E | emitter TR2 | ☐1 ☐2 ☐3 ——— ————————————————————————————————— | |
| 5 | В | base TR2 | TSSOP6 (SOT363) | 1 2 3 |
| 6 | С | collector TR1 | | sym018 |

6. Ordering information

Table 3. Ordering information

| Type number | | Package | | | | | |
|-------------|------------|---------|--|---------|--|--|--|
| | | Name | Description | Version | | | |
| | PMBT4403YS | TSSOP6 | plastic surface-mounted package; 6 leads | SOT363 | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| | [1] |
| PMBT4403YS | BJ% |

[1] % = placeholder for manufacturing site code

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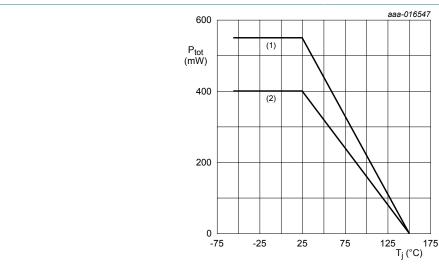
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|------|------|
| Per transis | tor | | | | | |
| V _{CBO} | collector-base voltage | open emitter | | - | -40 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -40 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| I _C | collector current | | | - | -600 | mA |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | -800 | mA |
| I _{BM} | peak base current | | | - | -200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 250 | mW |
| | | | [2] | - | 300 | mW |
| Per device | | | | | | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 400 | mW |
| | | | [2] | - | 550 | mW |
| T _j | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for collector 1 cm²



(1) FR4 PCB; mounting pad for collector 1 cm²

(2) FR4 PCB; standard footprint

Fig. 1. Per device: Power derating curves SOT363 (SC-88)

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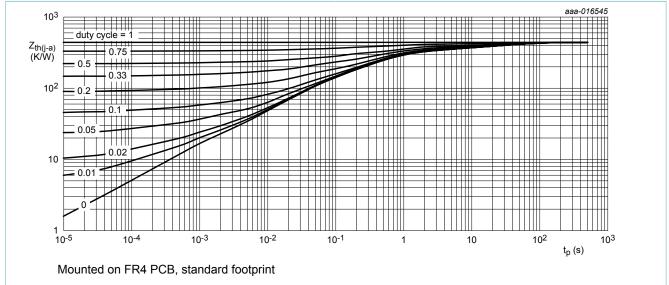
40V, 600 mA double PNP switching transistor

Thermal characteristics

Thermal characteristics Table 6.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|--------------------------|-------------|-----|-----|-----|-----|------|
| Per transist | tor | | | | | | |
| R _{th(j-a)} | thermal resistance | in free air | [1] | - | - | 500 | K/W |
| | from junction to ambient | | [2] | - | - | 417 | K/W |
| Per device | | | | | | | |
| R _{th(j-a)} | thermal resistance | in free air | [1] | - | - | 313 | K/W |
| | from junction to ambient | | [2] | - | - | 227 | K/W |

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for collector 1 cm²



Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; Fig. 2. typical values

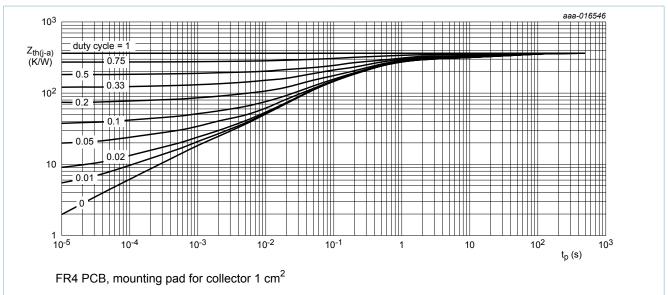


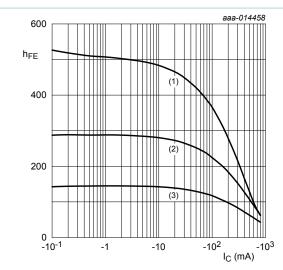
Fig. 3. Per Transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

40V, 600 mA double PNP switching transistor

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|--|-----|-----|------|------|
| Per transisto | or | | | | | |
| I _{CBO} | collector-base cut-off | V _{CB} = -40 V; I _E = 0 A; T _{amb} = 25 °C | - | - | -50 | nA |
| | current | $V_{CB} = -40 \text{ V}; I_E = 0 \text{ A}; T_j = 125 ^{\circ}\text{C}$ | - | - | -10 | μA |
| I _{EBO} | emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C | - | - | -50 | nA |
| h _{FE} | DC current gain | V _{CE} = -1 V; I _C = -0.1 mA; T _{amb} = 25 °C | 30 | - | - | |
| | | V_{CE} = -1 V; I_{C} = -1 mA; T_{amb} = 25 °C | 60 | - | - | |
| | | V_{CE} = -1 V; I_{C} = -10 mA; T_{amb} = 25 °C | 100 | - | - | |
| | | V_{CE} = -2 V; I_{C} = -150 mA; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 100 | - | 300 | |
| | | V_{CE} = -2 V; I_{C} = -500 mA; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | 20 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | I_C = -150 mA; I_B = -15 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_{amb} = 25 °C | - | - | -400 | mV |
| | | I_C = -500 mA; I_B = -50 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_{amb} = 25 °C | - | - | -750 | mV |
| V _{BEsat} | base-emitter saturation voltage | I_C = -150 mA; I_B = -15 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_{amb} = 25 °C | - | - | -950 | mV |
| | | I_C = -500 mA; I_B = -50 mA; $t_p \le 300$ μs; $δ \le 0.02$; T_{amb} = 25 °C | - | - | -1.3 | V |
| t _d | delay time | I _C = -150 mA; I _{Bon} = -15 mA; | - | - | 15 | ns |
| t _r | rise time | I _{Boff} = 15 mA; T _{amb} = 25 °C | - | - | 30 | ns |
| t _{on} | turn-on time | | - | - | 40 | ns |
| t _s | storage time | | - | - | 300 | ns |
| t _f | fall time | | - | - | 50 | ns |
| t _{off} | turn-off time | | - | - | 350 | ns |
| C _C | collector capacitance | V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C | - | - | 8.5 | pF |
| C _E | emitter capacitance | V_{EB} = -500 mV; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; f = 25 °C | - | - | 35 | pF |
| f _T | transition frequency | V_{CE} = -10 V; I_{C} = -20 mA; f = 100 MHz; T_{amb} = 25 °C | 200 | - | - | MHz |



$$V_{CE} = -2 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values

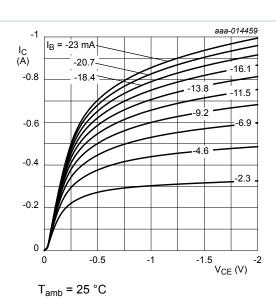
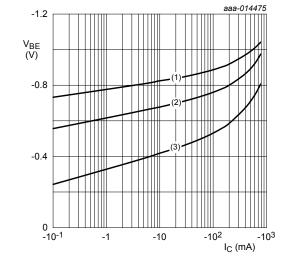


Fig. 5. Collector current as a function of collectoremitter voltage; typical values



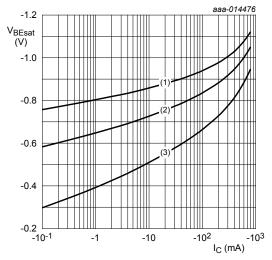
$$V_{CE} = -2 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. Base-emitter voltage as a function of collector current; typical values



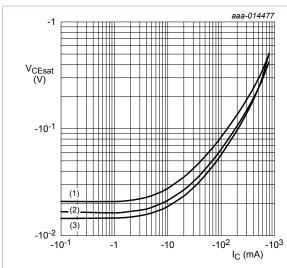
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values



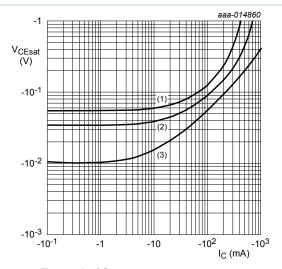
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

(1)
$$I_C/I_B = 100$$

(2)
$$I_{\rm C}/I_{\rm B} = 50$$

(3)
$$I_C/I_B = 10$$

Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

40V, 600 mA double PNP switching transistor

11. Test information

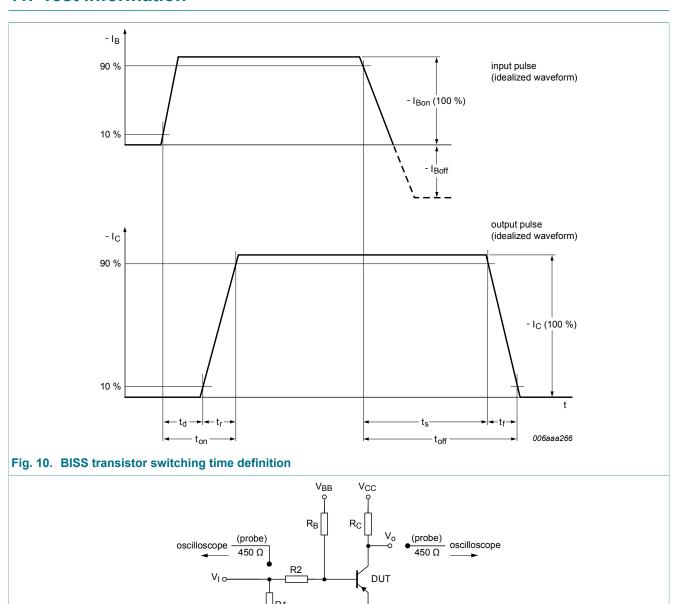


Fig. 11. Test circuit for switching times

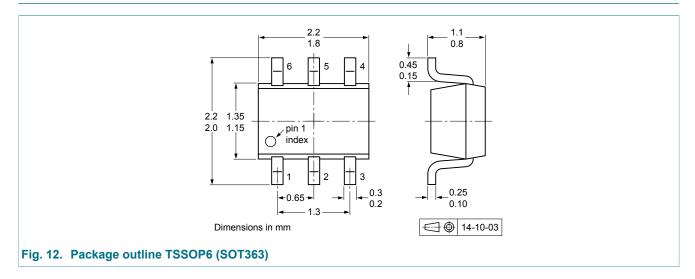
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This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

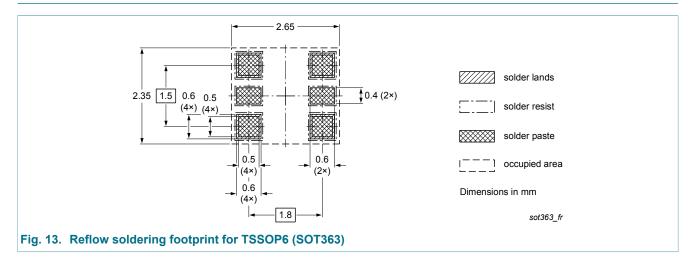
mgd624

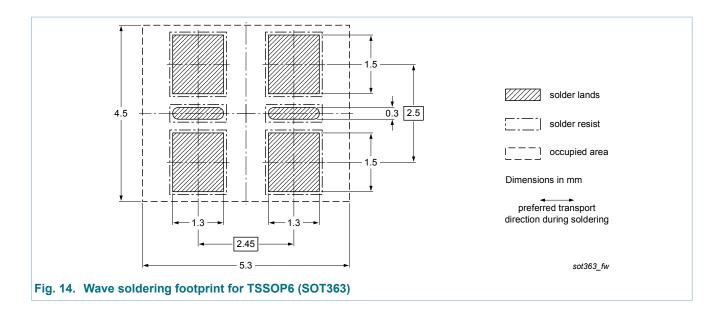
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12. Package outline



13. Soldering





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14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|--------------------|---------------|------------|
| PMBT4403YS v.1 | 20150702 | Product data sheet | - | - |

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|--------------------|---|
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